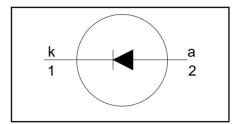
Rectifier diodes fast, soft-recovery

BY229F, BY229X series

FEATURES

- Low forward volt drop
- Fast switching
- Soft recovery characteristic
- High thermal cycling performance
 Isolated mounting tab

SYMBOL



QUICK REFERENCE DATA

$$V_R = 200 \text{ V/ } 400 \text{ V/ } 600 \text{ V/} 800 \text{ V}$$

$$I_{F(AV)} = 8 \text{ A}$$

$$I_{FSM} \le 60 \text{ A}$$

$$t_{rr} \le 135 \text{ ns}$$

GENERAL DESCRIPTION

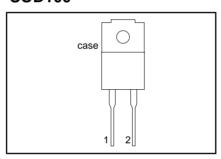
Glass-passivated double diffused rectifier diodes featuring low forward voltage drop, fast reverse recovery and soft recovery characteristic. The devices are intended for use in TV receivers, monitors and switched mode power supplies.

The BY229F series is supplied in the conventional leaded SOD100 package. The BY229X series is supplied in the conventional leaded SOD113 package.

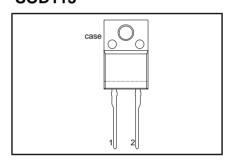
PINNING

| DESCRIPTION | |
|-------------|--|
| cathode | |
| anode | |
| isolated | |
| | |
| | |

SOD100



SOD113



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | | | UNIT | |
|--|--|---|-------------|-------------------|-------------------|-------------------|-------------------|------------------|
| V_{RSM} | Peak non-repetitive reverse | BY229F- / BY229X- | - | 200 200 | 400 400 | 600 600 | 800 800 | V |
| V _{RRM} V _{RWM} V _R | voltage Peak repetitive reverse voltage Crest working reverse voltage Continuous reverse voltage | | - - - | 200 150 150 | 400 300 300 | 600 500 500 | 800 600 600 | V V V |
| I _{F(AV)} | Average forward current ¹ | square wave; $\delta = 0.5$; $T_{hs} \le 83 ^{\circ}C$ | - | 8 | | Α | | |
| | | $T_{hs} = 0.5$ C sinusoidal; $a = 1.57$; $T_{hs} \le 90$ °C | - | | 7 | 7 | | Α |
| I _{F(RMS)} | RMS forward current | I hs = 50 0 | _ | | 1 | 1 | | Α |
| I _{FRM} | Peak repetitive forward current | $t = 25 \mu s; \delta = 0.5;$ $T_{hs} \le 83 ^{\circ} C$ | - | | 1 | 6 | | А |
| I _{FSM} | Peak non-repetitive forward | t = 10 ms | - | 60 | | Α | | |
| | current | t = 8.3 ms sinusoidal; T _j = 150 °C prior to surge; with | - | | 6 | 6 | | A |
| l ² t | I ² t for fusing | reapplied V _{RWM(max)} t = 10 ms | _ | | 1 | 8 | | A ² s |
| T_{stg} | Storage temperature | | -40 | | | 50 | | l °C ∣ |
| T _j | Operating junction temperature | | - | 150 | | °C | | |

^{1.} Neglecting switching and reverse current losses.

Philips Semiconductors Product specification

Rectifier diodes fast, soft-recovery

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ISOLATION LIMITING VALUE & CHARACTERISTIC

 T_{hs} = 25 °C unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|-------------------|---|---|------|------|------|----------|
| V _{isol} | Peak isolation voltage from both terminals to external heatsink | SOD100 package; R.H. ≤ 65%; clean and dustfree | ı | 1 | 1500 | V |
| V _{isol} | R.M.S. isolation voltage from both terminals to external heatsink | SOD113 package; f = 50-60 Hz; sinusoidal waveform; R.H. ≤ 65%; clean and dustfree | - | - | 2500 | V |
| C _{isol} | Capacitance from pin 1 to external heatsink | f = 1 MHz | - | 10 | - | pF |

THERMAL RESISTANCES

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|----------------------|---|--|------|------|------------|------------|
| R _{th j-hs} | Thermal resistance junction to heatsink | with heatsink compound without heatsink compound | | | 4.8 7.2 | K/W K/W |
| R _{th j-a} | Thermal resistance junction to ambient | in free air. | - | 55 | - | K/W |

STATIC CHARACTERISTICS

T_i = 25 °C unless otherwise stated

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|----------------|-----------------|--|------|------|------|------|
| V _F | Forward voltage | $I_F = 20 \text{ A}$ | - | 1.5 | 1.85 | V |
| I _R | Reverse current | $V_R = V_{RWM}$; $T_i = 125 \text{ °C}$ | | 0.1 | 0.4 | mA |

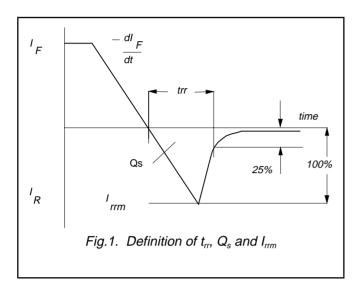
DYNAMIC CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|--------------------------|-------------------------|--|------|------------------|------------------|------------------|
| t_{rr} Q_s dl_R/dt | Reverse recovery charge | $\begin{array}{l} I_F = 1 \text{ A; } V_R \geq 30 \text{ V; } -dI_F/dt = 50 \text{ A/}\mu\text{s} \\ I_F = 2 \text{ A; } V_R \geq 30 \text{ V; } -dI_F/dt = 20 \text{ A/}\mu\text{s} \\ I_F = 2 \text{ A; } -dI_F/dt = 20 \text{ A/}\mu\text{s} \end{array}$ | | 100 0.5 50 | 135 0.7 60 | ns μC A/μs |

Rectifier diodes fast, soft-recovery

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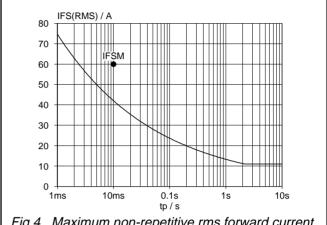


Fig.4. Maximum non-repetitive rms forward current. $I_F = f(t_p)$; sinusoidal current waveform; $T_j = 150^{\circ} C$ prior to surge with reapplied V_{RWM} .

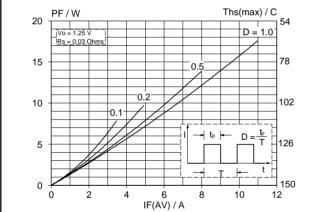


Fig.2. Maximum forward dissipation, $P_F = f(I_{F(AV)})$; square wave current waveform; parameter D = duty $cycle = t_p/T$.

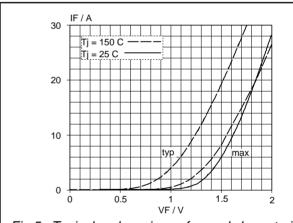


Fig.5. Typical and maximum forward characteristic; $I_F = f(V_F)$; parameter T_j

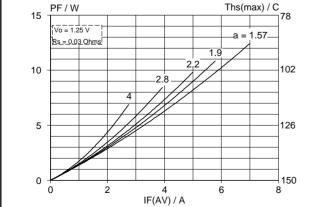
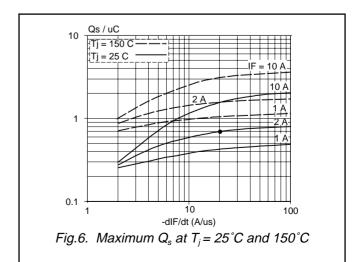
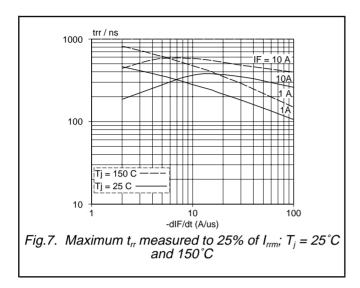


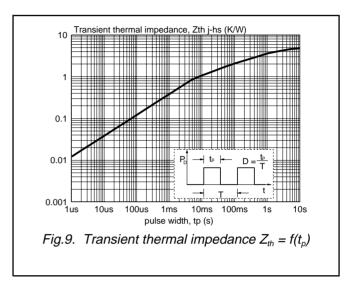
Fig.3. Maximum forward dissipation, $P_F = f(I_{F(AV)})$; sinusoidal current waveform; parameter a = form factor $= I_{F(RMS)}/I_{F(AV)}$.



Rectifier diodes fast, soft-recovery

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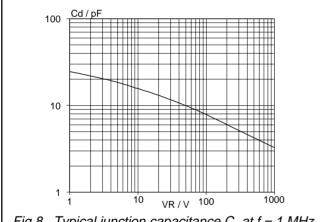
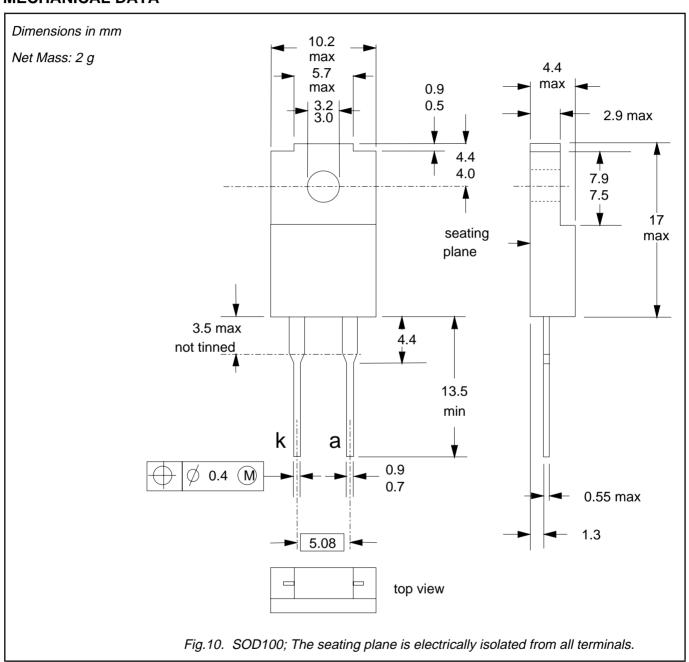


Fig.8. Typical junction capacitance C_d at f = 1 MHz, $T_j = 25^{\circ}C$

Rectifier diodes fast, soft-recovery BY229F, BY229X series

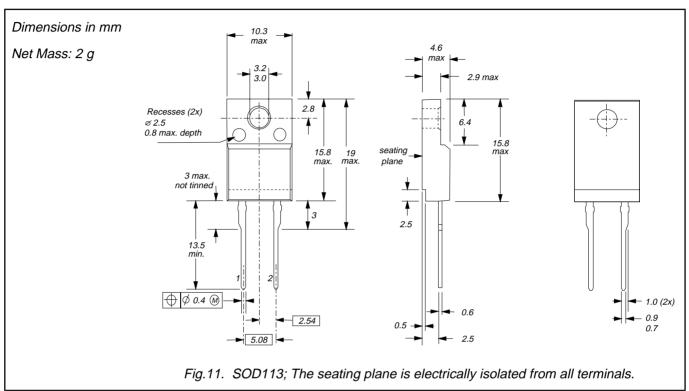
MECHANICAL DATA



- Refer to mounting instructions for F-pack envelopes.
 Epoxy meets UL94 V0 at 1/8".

Rectifier diodes fast, soft-recovery BY229F, BY229X series

MECHANICAL DATA



Notes

- Refer to mounting instructions for F-pack envelopes.
 Epoxy meets UL94 V0 at 1/8".

Philips Semiconductors Product specification

Rectifier diodes fast, soft-recovery

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DEFINITIONS

| Data sheet status | |
|---------------------------|---|
| Objective specification | This data sheet contains target or goal specifications for product development. |
| Preliminary specification | This data sheet contains preliminary data; supplementary data may be published later. |
| Product specification | This data sheet contains final product specifications. |
| | |

Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

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